L Number	Hits	Search Text	DB	Time stamp
1	231191	light-emitting) (light near emitting	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:24
2	72034	(light-emitting) (light near emitting) and (recess trench gap cavity opening groove)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:25
3	24977	((light-emitting) (light near emitting) and (recess trench gap cavity opening groove)) and sensor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:25
4	17854	(((light-emitting) (light near emitting) and (recess trench gap cavity opening groove)) and sensor) and (substrate wafer base (auxiliary near carrier))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:27
5	13185	((((light-emitting) (light near emitting) and (recess trench gap cavity opening groove)) and sensor) and (substrate wafer base (auxiliary near carrier))) and (lens optical)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:27
6	61	(((((light-emitting) (light near emitting) and (recess trench gap cavity opening groove)) and sensor) and (substrate wafer base (auxiliary near carrier))) and (lens optical) and (system near carrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:28
8	7	((((((light-emitting) (light near emitting) and (recess trench gap cavity opening groove)) and sensor) and (substrate wafer base (auxiliary near carrier))) and (lens optical)) and (system near carrier)) and optoelectronic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/01 14:29